TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK882

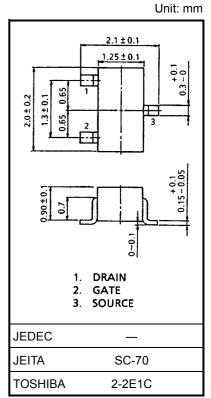
FM Tuner, VHF RF Amplifier Applications

• Low reverse transfer capacitance: $C_{rss} = 0.025 \text{ pF}$ (typ.)

- Low noise figure: NF = 1.7dB (typ.)
- High power gain: G_{ps} = 28dB (typ.)
- Recommend operation voltage: $5 \sim 15 \text{ V}$

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	20	V
Gate-source voltage	V _{GS}	±5	V
Drain current	I _D	30	mA
Drain power dissipation	PD	100	mW
Channel temperature	T _{ch}	125	°C
Storage temperature	T _{stg}	-55~125	°C

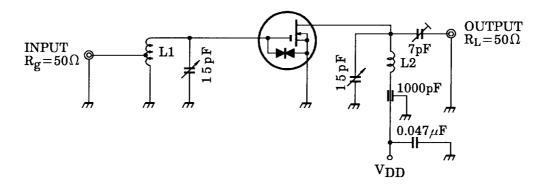


Weight: 0.006 g (typ.)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{DS}=0,V_{GS}=\pm5~V$			±50	nA
Drain-source voltage	V _{DSX}	$V_{GS} = -4 \ V, \ I_D = 100 \ \mu A$	20	_	_	V
Drain current	I _{DSS} (Note)	$V_{DS} = 10 V, V_{GS} = 0$	3	_	14	mA
Gate-source cut-off voltage	V _{GS (OFF)}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 100 \mu\text{A}$		_	-2.5	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 10 V, V_{GS} = 0, f = 1 \text{ kHz}$		10		mS
Input capacitance	C _{iss}		_	3.0	4.3	pF
Reverse transfer capacitance	C _{rss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz		0.025	0.04	pF
Power gain	G _{ps}	$\lambda = 10 \lambda f = 100 \text{ MHz} (Figure 1)$	20	28	_	dB
Noise figure	NF	V _{DS} = 10 V, f = 100 MHz (Figure 1)		1.7	3.0	dB

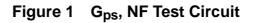
Electrical Characteristics (Ta = 25°C)

Note: IDSS classification Y: 3.0~7.0 mA, GR: 6.0~14.0 mA

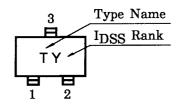


L1: 1.0 mm ϕ silver plated copper wire 4.0 T, 8 mm ϕ ID TAP at 1.0 T from coil end

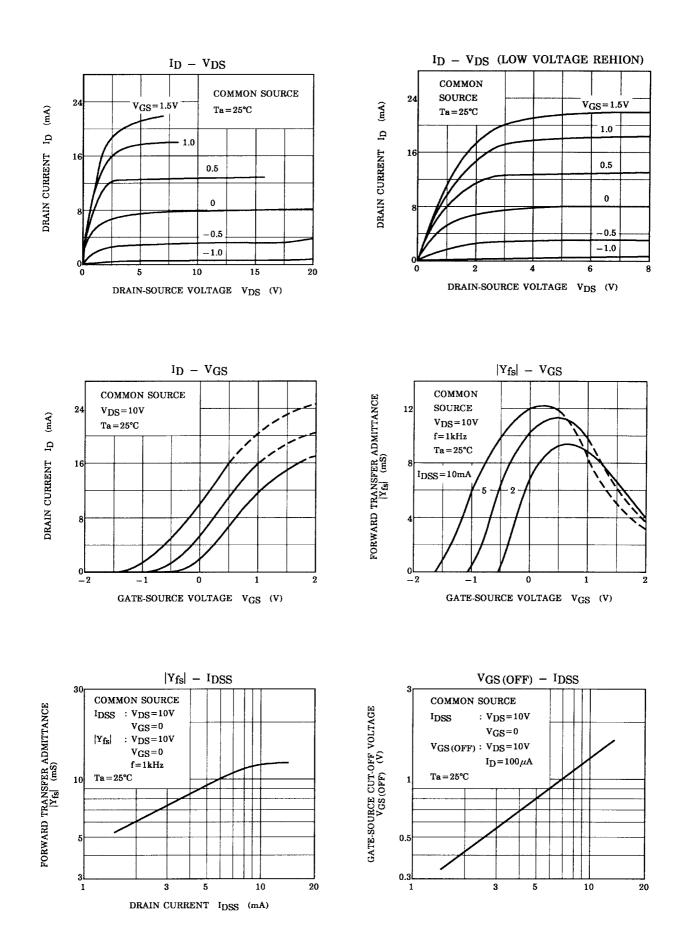
L2: 1.0 mm ϕ silver plated copper wire 3.0 T, 8 mm ϕ ID, 10 mm length



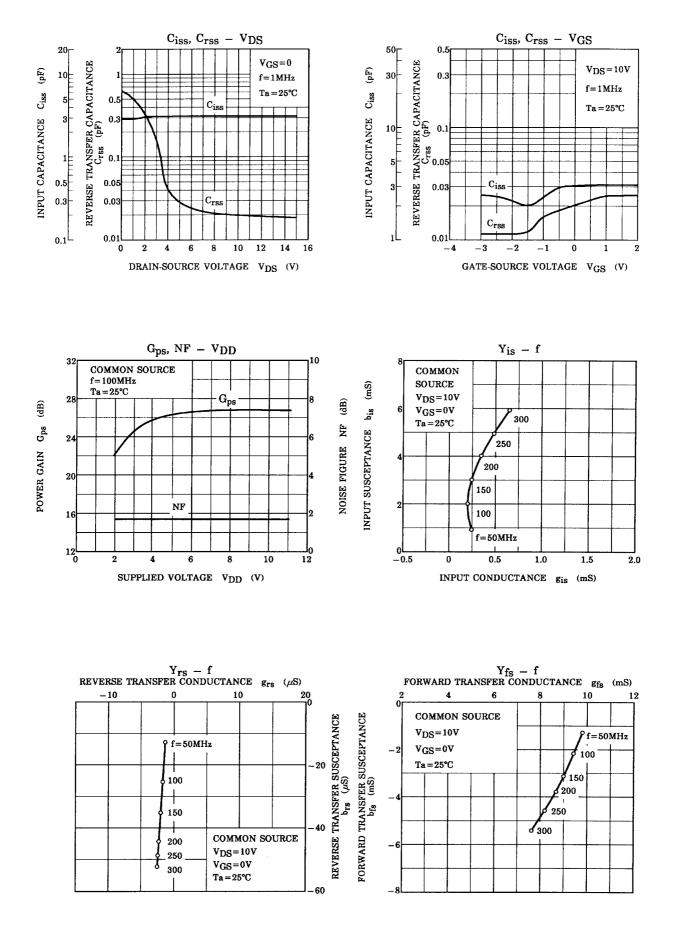
Marking



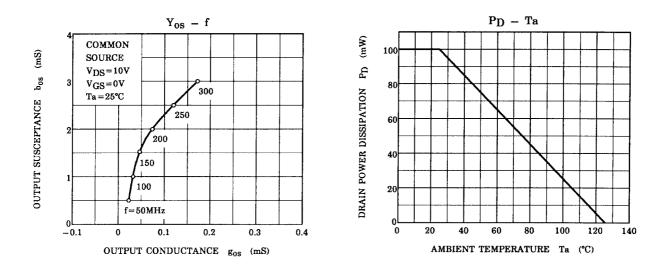
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